

NCV33152DR2G

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Data Sheet

HIGH SPEED DUAL MOSFET DRIVERS, MOSFET & Power Driver ICs 1.5A High Speed Dual Non-Inverting MOSFET

Manufacturers	ON Semiconductor, LLC	E. E.
Package/Case	SOIC-8	E
Product Type	Power Management ICs	EEE
RoHS	Rohs	
Lifecycle		Images are for reference only
Please submit RFQ for NCV33152DR2G or Email to us: sales@ovaga.com We will contact you in 12 hours.		

General Description

The MC34152/MC33152 are dual noninverting high speed drivers specifically designed for applications that require low current digital signals to drive large capacitive loads with high slew rates. These devices feature low input current making them CMOS/LSTTL logic compatible, input hysteresis for fast output switching that is independent of input transition time, and two high current totem pole outputs ideally suited for driving power MOSFETs. Also included is an undervoltage lockout with hysteresis to prevent system erratic operation at low supply voltages. Typical applications include switching power supplies, dc-to-dc converters, capacitor charge pump voltage doublers/inverters, and motor controllers. This device is available in dual-in-line and surface mount packages.

Features

Two Independent Channels with 1.5 A Totem Pole Outputs

Output Rise and Fall Times of 15 ns with 1000 pF Load

CMOS/LSTTL Compatible Inputs with Hysteresis

Undervoltage Lockout with Hysteresis

Low Standby Current

Efficient High Frequency Operation

Enhanced System Performance with Common Switching Regulator Control ICs

Pb-Free Packages are Available

Application

ONSEMI

Related Products



NCP603SN330T1G ON Semiconductor, LLC TSOP-5



NCP1234AD65R2G ON Semiconductor, LLC



SOIC-7



SOT-23-5



NCV4274ADS50R4G ON Semiconductor, LLC SOT263









NCP1399ACDR2G

ON Semiconductor, LLC SOP16

NCP3334DADJR2G

ON Semiconductor, LLC SOIC-8

NCP330MUTBG

ON Semiconductor, LLC UDFN-4

NCP1252ADR2G

ON Semiconductor, LLC SOIC-8